MA3S781D (MA781WA), MA3S781E (MA781WK)

Silicon epitaxial planar type

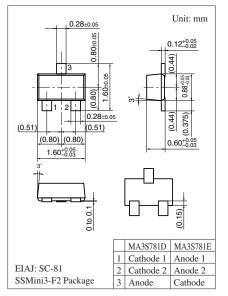
For high speed switching

Features

- Two MA3S781 (MA781) is contained in one package
- High-density mounting is possible
- \bullet Low forward voltage $V_{\rm F}$

Parameter		Rating	Unit
Reverse voltage		30	V
Maximum peak reverse voltage		30	V
Single	I _F	30	mA
Double		20	
Single	I _{FM}	150	mA
Double		110	
re	Tj	125	°C
Storage temperature		-55 to +125	°C
	rse voltage Single Double Single Double re	$\begin{tabular}{ c c c c } \hline & & & & & & \\ \hline & & & & & & \\ \hline Single & & & & & \\ \hline Double & & & & & \\ \hline re & & & T_j & & \\ \hline \end{tabular}$	$\begin{tabular}{ c c c c c } \hline V_R & V_R & 30 \\ \hline V_{RM} & 30 \\ \hline Single & I_F & 30 \\ \hline Double & 20 \\ \hline Single & I_{FM} & 150 \\ \hline Double & 110 \\ \hline re & T_j & 125 \\ \hline \end{tabular}$

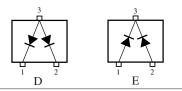
Absolute Maximum Ratings $T_a = 25^{\circ}C$



Marking Symbol

• MA3S781D: M2P • MA3S781E: M2R

Internal Connection



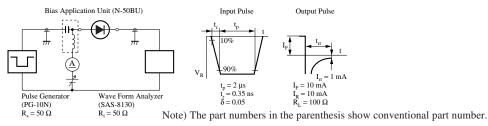
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	V _{F1}	$I_F = 1 \text{ mA}$			0.4	V
	V _{F2}	I _F = 30 mA			1.0	
Reverse current	I _R	$V_R = 30 V$			1	μΑ
Terminal capacitance	Ct	$V_{R} = 1 V, f = 1 MHz$		1.5		pF
Reverse recovery time *	t _{rr}	$I_F = I_R = 10 \text{ mA}$ $I_{rr} = 1 \text{ mA}, R_L = 100 \Omega$		1.0		ns
Detection efficiency	η	$V_{IN} = 3 V_{(peak)}, f = 30 \text{ MHz}$ $R_L = 3.9 \text{ k}\Omega, C_L = 10 \text{ pF}$		65		%

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

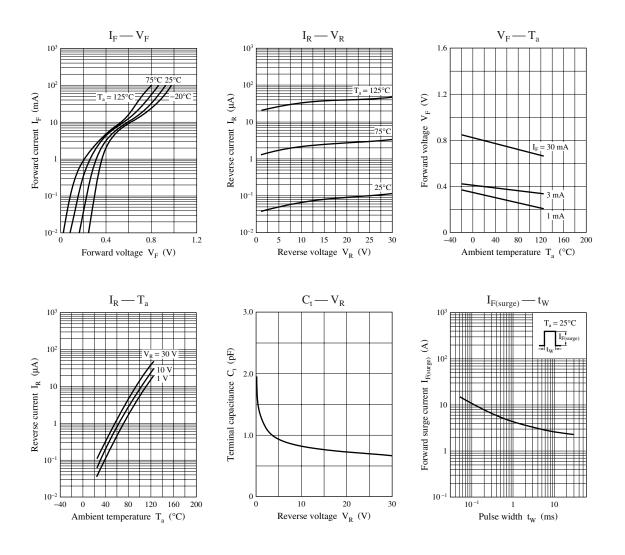
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.

3. Absolute frequency of input and output is 2 GHz. 4. *: trr measurement circuit



Panasonic



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